

CLAIMS

- 1 1. 1. A method for fabricating a magnetic head including a spin valve sensor, comprising
2 the steps of:
3 fabricating a first electrical insulation layer (G1) above a first magnetic shield layer (S1);
4 fabricating a plurality of spin valve sensor layers above said G1 layer, said spin valve
5 sensor layers including a seed layer, a PtMn antiferromagnetic layer, at least one pinned
6 magnetic layer and at least one free magnetic layer;
7 wherein said seed layer is a three part seed layer comprised of Al_2O_3 , NiMnO and
8 NiFeCr.
- 1 2. A method for fabricating a magnetic head as described in claim 1 wherein said NiFeCr
2 seed layer portion is fabricated to have a thickness of approximately 20 Å.
- 1 3. A method for fabricating a magnetic head as described in claim 1 wherein said spin valve
2 sensor layers include at least one pinned magnetic layer having a composition including CoFe
3 and at least one spacer layer having a composition including Cu, and at least one free magnetic
4 layer having a composition including NiFe.
- 1 4. A method for fabricating a magnetic head as described in claim 1 wherein the Cr
2 concentration of said NiFeCr layer is from approximately 35 at.% to approximately 46 at.%.
- 1 5. A method for fabricating a magnetic head as described in claim 4 wherein the Cr
2 concentration of said NiFeCr layer is approximately 38 at.%.

1 6. A method for fabricating a magnetic head as described in claim 5 wherein the
2 composition of said NiFeCr layer is approximately $\text{Ni}_{49.5} \text{Fe}_{12.5} \text{Cr}_{38}$.

1 7. A method for fabricating a magnetic head including a spin valve sensor, comprising the steps
2 of:

3 fabricating a first electrical insulation layer (G1) above a first magnetic shield layer (S1);

4 fabricating a plurality of spin valve sensor layers above said G1 layer, said spin valve
5 sensor layers including a seed layer, a PtMn antiferromagnetic layer, at least one pinned
6 magnetic layer and at least one free magnetic layer;

7 wherein said seed layer is comprised of Al_2O_3 , NiMnO, NiFeCr layer portions, and
8 wherein said NiFeCr layer is fabricated by depositing it to a first thickness and subsequently
9 etching it back to a final thickness before the fabrication of said PtMn layer.

1 8. A method for fabricating a magnetic head as described in claim 7 wherein said NiFeCr
2 layer is fabricated to have a final thickness of from approximately 10 Å to approximately 40 Å.

1 9. A method for fabricating a magnetic head as described in claim 8 wherein said NiFeCr
2 seed layer is fabricated to have a final thickness of from approximately 15 Å to approximately 35
3 Å.

1 10. A method for fabricating a magnetic head as described in claim 9 wherein said NiFeCr
2 layer is fabricated to have a final thickness of approximately 20 Å.

1 11. A method for fabricating a magnetic head as described in claim 7 wherein said first
2 thickness of said NiFeCr layer is from approximately 15 Å to approximately 45 Å and it is
3 etched back a thickness of from approximately 5 Å to approximately 15 Å.

1 12. A method for fabricating a magnetic head as described in claim 11 wherein said first
2 thickness is approximately 30 Å and said final thickness is approximately 20 Å.

1 13. A method for fabricating a magnetic head as described in claim 7 wherein said spin valve
2 sensor layers include at least one pinned magnetic layer having a composition including CoFe
3 and at least one spacer layer having a composition including Cu, and at least one free magnetic
4 layer having a composition including NiFe.

1 14. A method for fabricating a magnetic head as described in claim 7 wherein the Cr
2 concentration of said NiFeCr layer is from approximately 35 at.% to approximately 46 at.%.

1 15. A method for fabricating a magnetic head as described in claim 14 wherein the Cr
2 concentration of said NiFeCr layer is approximately 38 at.%.

1 16. A method for fabricating a magnetic head as described in claim 15 wherein the
2 composition of said NiFeCr layer is approximately $\text{Ni}_{49.5} \text{Fe}_{12.5} \text{Cr}_{38}$.

1 17. A method for fabricating a magnetic head as described in claim 7 wherein said first
2 thickness is from 15 to 45 Å, and it is etched back a thickness of from 5 to 15 Å, and wherein the

3 Cr concentration of said NiFeCr layer composition is from approximately 35 at.% to
4 approximately 46 at.%.

1 18. A magnetic head including a spin valve sensor comprising:
2 a magnetic shield layer (S1) being fabricated above a substrate base;
3 a first electrical insulation layer (G1) being fabricated above said S1 layer;
4 a spin valve sensor structure being disposed above said G1 layer;
5 wherein said spin valve sensor structure includes a seed layer being fabricated above said
6 G1 layer, a PtMn layer being disposed above said seed layer and at least one pinned magnetic
7 layer and at least one free magnetic layer being disposed above said PtMn layer; and
8 wherein said seed layer includes an Al₂O₃ layer, an NiMnO layer, and an NiFeCr layer.

1 19. A magnetic head as described in claim 18 wherein said NiFeCr layer is formed with a
2 thickness of approximately 20 Å.

1 20. A magnetic head as described in claim 18 wherein the Cr concentration of said NiFeCr
2 layer is from approximately 35 at.% to approximately 46 at.%.

1 21. A magnetic head as described in claim 19 wherein the Cr concentration of said NiFeCr
2 layer is approximately 38 at.%.

1 22. A magnetic head as described in claim 21 wherein the composition of said NiFeCr layer
2 is approximately Ni_{49.5} Fe_{12.5} Cr₃₈.

1 23. A magnetic head including a spin valve sensor comprising:
2 a magnetic shield layer (S1) being fabricated above a substrate base;
3 a first electrical insulation layer (G1) being fabricated above said S1 layer;
4 a spin valve sensor structure being disposed above said G1 layer;
5 wherein said spin valve sensor structure includes a seed layer being fabricated above said
6 G1 layer, a PtMn layer being disposed above said seed layer and at least one pinned magnetic
7 layer and at least one free magnetic layer being disposed above said PtMn layer; and
8 wherein said seed layer has an upper surface comprised of NiFeCr having an etched
9 crystalline structure.

1 24. A magnetic head as described in claim 23 wherein said NiFeCr layer is formed with a
2 thickness of from approximately 10 Å to approximately 40 Å.

1 25. A magnetic head as described in claim 23 wherein said NiFeCr seed layer is formed with
2 a thickness of from approximately 15 Å to approximately 35 Å.

1 26. magnetic head as described in claim 23 wherein said NiFeCr layer is formed with a
2 thickness of approximately 20 Å.

1 27. A magnetic head as described in claim 23 wherein the Cr concentration of said NiFeCr
2 layer is from approximately 35 at.% to approximately 46 at.%.

1 28. A magnetic head as described in claim 27 wherein the Cr concentration of said NiFeCr
2 layer is approximately 38 at.%.

1 29. A magnetic head as described in claim 28 wherein the composition of said NiFeCr layer
2 is approximately $\text{Ni}_{49.5} \text{Fe}_{12.5} \text{Cr}_{38}$.

1 30. A magnetic head as described in claim 23 wherein said spin valve sensor structure
2 includes at least one PtNm antiferromagnetic layer, at least one pinned magnetic layer having a
3 composition which includes CoFe, at least one spacer layer having a composition which includes
4 Cu, and at least one free magnetic layer having a composition which includes NiFe.

1 31. A hard disk drive, including at least one magnetic head having a read head portion
2 comprising:

3 a magnetic shield layer (S1) being fabricated above a substrate base;

4 a first electrical insulation layer (G1) being fabricated above said S1 layer;

5 a spin valve sensor structure being disposed above said G1 layer;

6 wherein said spin valve sensor structure includes a seed layer being fabricated above said
7 G1 layer, a PtMn layer being fabricated above said seed layer and at least one pinned magnetic
8 layer and at least one free magnetic layer; and

9 wherein said seed layer includes an Al_2O_3 layer, an NiMnO layer and an NiFeCr layer.

1 32. A hard disk drive as described in claim 31 wherein said NiFeCr layer has a thickness of
2 approximately 20 Å.

1 33. A hard disk drive as described in claim 31 wherein the Cr concentration of said NiFeCr
2 layer is from approximately 35 at.% to approximately 46 at.%.

1 34. A hard disk drive as described in claim 33 wherein the Cr concentration of said NiFeCr
2 layer is approximately 38 at.%.

1 35. A hard disk drive as described in claim 34 wherein the composition of said NiFeCr layer
2 is approximately $\text{Ni}_{49.5} \text{Fe}_{12.5} \text{Cr}_{38}$.

1 36. A hard disk drive, including at least one magnetic head having a read head portion
2 comprising:

3 a magnetic shield layer (S1) being fabricated above a substrate base;

4 a first electrical insulation layer (G1) being fabricated above said S1 layer;

5 a spin valve sensor structure being disposed above said G1 layer;

6 wherein said spin valve sensor structure includes a seed layer being fabricated above said

7 G1 layer, a PtMn layer being fabricated above said seed layer and at least one pinned magnetic
8 layer and at least one free magnetic layer; and

9 wherein said seed layer has an upper surface comprised of NiFeCr having an etched
10 crystalline structure.

1 37. A hard disk drive as described in claim 36 wherein NiFeCr seed layer is formed with a
2 thickness of from approximately 10 Å to approximately 40 Å.

1 38. A hard disk drive as described in claim 36 wherein said NiFeCr seed layer is formed with
2 a thickness of from approximately 15 Å to approximately 35 Å.

1 39. A hard disk drive as described in claim 36 wherein said NiFeCr layer is formed with a
2 thickness of approximately 20 Å.

1 40. A hard disk drive as described in claim 36 wherein the Cr concentration of said NiFeCr
2 layer is from approximately 35 at.% to approximately 46 at.%.

1 41. A hard disk drive as described in claim 40 wherein the Cr concentration of said NiFeCr
2 layer is approximately 38 at.%.

1 42. A hard disk drive as described in claim 41 wherein the composition of said NiFeCr layer
2 is approximately $\text{Ni}_{49.5}\text{Fe}_{12.5}\text{Cr}_{38}$.

1 43. A hard disk drive as described in claim 36 wherein said spin valve sensor structure
2 includes at least one PtNm antiferromagnetic layer, at least one pinned magnetic layer having a
3 composition which includes CoFe, at least one spacer layer having a composition which includes
4 Cu, and at least free magnetic layer having a composition which includes NiFe.